NSN 5961-01-085-8223

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-085-8223 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.335 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 drain to source voltage and -15.0 gate to source threshold voltage and -15.0 gate non-trigger voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**